



60 V, 3 A NPN low VCEsat (BISS) transistor 26 February 2014

Product data sheet

1. General description

NPN low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5360Z.

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High energy efficiency due to less heat generation
- AEC-Q101 qualified

3. Applications

- DC-to-DC conversion
- Supply line switching
- Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver (e.g. relays, buzzers and motors)

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	60	V
I _C	collector current			-	-	3	А
I _{CM}	peak collector current	$t_p \le 1 \text{ ms}; \text{ single pulse}$		-	-	6	А
R _{CEsat}	collector-emitter saturation resistance	I_{C} = 2 A; I_{B} = 200 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	140	mΩ



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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	2,4
2	С	collector		1
3	E	emitter		· •
4	С	collector	☐1	3 sym016

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PBSS4360Z	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PBSS4360Z	P4360Z

8. Limiting values

Table 5.Limiting values

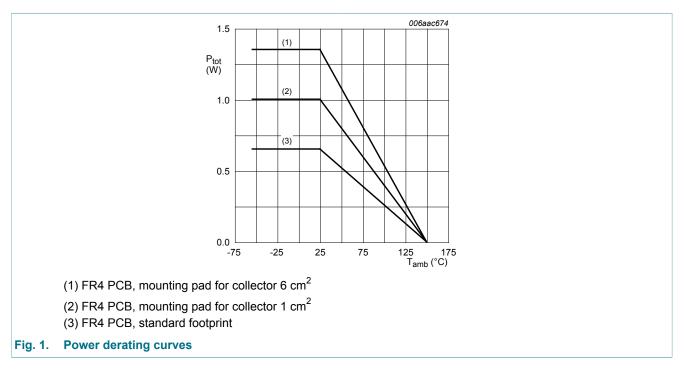
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CBO}	collector-base voltage	open emitter		-	80	V
V _{CEO}	collector-emitter voltage	open base		-	60	V
V _{EBO}	emitter-base voltage	open collector		-	7	V
I _C	collector current			-	3	А
I _{CM}	peak collector current	$t_p \le 1$ ms; single pulse		-	6	А
I _B	base current			-	500	mA
I _{BM}	peak base current	$t_p \le 1$ ms; single pulse		-	1	А
P _{tot}	total power dissipation		[1]	-	0.65	W
			[2]	-	1	W
			[3]	-	1.35	W

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Symbol	Parameter	Conditions		Min	Мах	Unit
			[4]	-	2	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².
- ^[4] Device mounted on an FR4 PCB, 70 µm single-sided copper, tin-plated, mounting pad for collector 6 cm².



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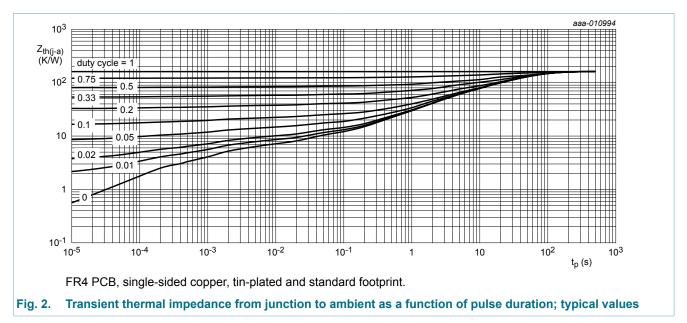
9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient	thermal resistance	in free air	[1]	-	-	192	K/W
		[2]	-	-	125	K/W	
	ampient		[3]	-	-	93	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	16	K/W

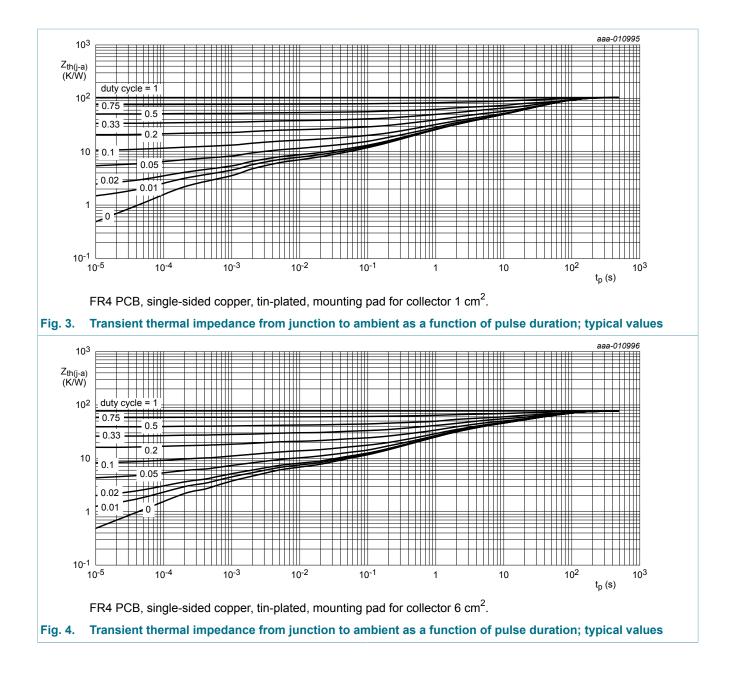
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².







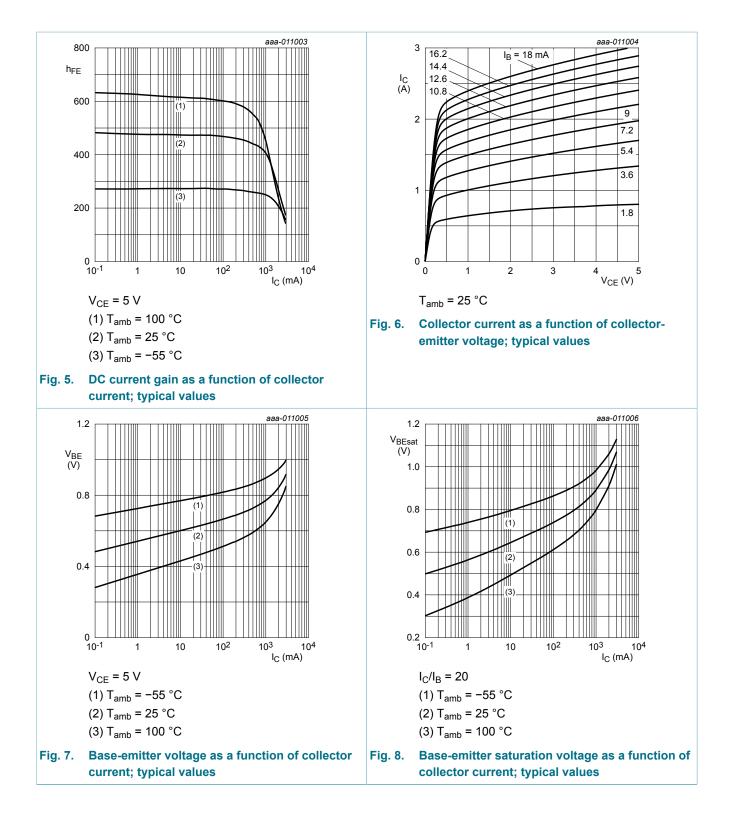
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10. Characteristics

Symbol	Parameter	Conditions	M	lin	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V_{CB} = 48 V; I _E = 0 A; T _{amb} = 25 °C	-		-	100	nA
	current	V_{CB} = 48 V; I _E = 0 A; T _j = 150 °C	-		-	50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = 48 V; V_{BE} = 0 V; T_{amb} = 25 °C	-		-	100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}; \text{ T}_{amb} = 25 \text{ °C}$	-		-	100	nA
h _{FE}	DC current gain	V_{CE} = 5 V; I _C = 50 mA; T _{amb} = 25 °C	2	200	-	-	
		$\begin{split} &V_{CE} = 5 \; V; \; I_{C} = 500 \; mA; \; pulsed; \\ &t_{p} \leq 300 \; \mus; \; \delta \leq 0.02; \; T_{amb} = 25 \; ^{\circ}C \end{split}$	2	200	-	-	
		$\label{eq:Vce} \begin{split} V_{CE} = 5 \text{ V; } I_C = 1 \text{ A; pulsed; } t_p \leq 300 \mu\text{s;} \\ \delta \leq 0.02; T_{amb} = 25 ^\circ\text{C} \end{split}$	2	200	-	-	
		$\label{eq:Vce} \begin{array}{l} V_{CE} = 5 \; V; \; I_{C} = 2 \; A; \; pulsed; \; t_{p} \leq 300 \; \mu s; \\ \delta \leq 0.02; \; T_{amb} = 25 \; ^{\circ} C \end{array}$	1	20	-	-	
		$\label{eq:Vce} \begin{array}{l} V_{CE} \texttt{=} \texttt{5} \; V; \; I_{C} \texttt{=} \texttt{3} \; A; \; \texttt{pulsed}; \; t_{p} \texttt{\leq} \texttt{300} \; \mu \texttt{s}; \\ \delta \texttt{\leq} \texttt{0.02}; \; T_{amb} \texttt{=} \texttt{25} \; ^{\circ} C \end{array}$	7	'5	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 500 mA; I_{B} = 50 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02; T_{amb} = 25 °C	-		-	75	mV
		$\begin{split} I_{C} &= 1 \text{ A}; I_{B} = 100 \text{ mA}; \text{ pulsed}; \\ t_{p} &\leq 300 \mu\text{s}; \delta \leq 0.02; T_{amb} = 25 ^{\circ}\text{C} \end{split}$	-		-	150	mV
		I_C = 2 A; I_B = 200 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-		-	275	mV
		I_C = 3 A; I_B = 300 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-		-	400	mV
R _{CEsat}	collector-emitter saturation resistance	I_C = 2 A; I_B = 200 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-		-	140	mΩ
V _{BEsat}	base-emitter saturation voltage	I_C = 1 A; I_B = 100 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-		-	1.2	V
V _{BEon}	base-emitter turn-on voltage	$\label{eq:Vce} \begin{split} V_{CE} &= 5 \text{ V; } I_C = 1 \text{ A; pulsed; } t_p \leq 300 \mu\text{s;} \\ \delta \leq 0.02; T_{amb} = 25 ^\circ\text{C} \end{split}$	-		-	1.1	V
f _T	transition frequency	V_{CE} = 10 V; I _C = 50 mA; f = 100 MHz; T _{amb} = 25 °C	7	5	145	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-		11	14	pF

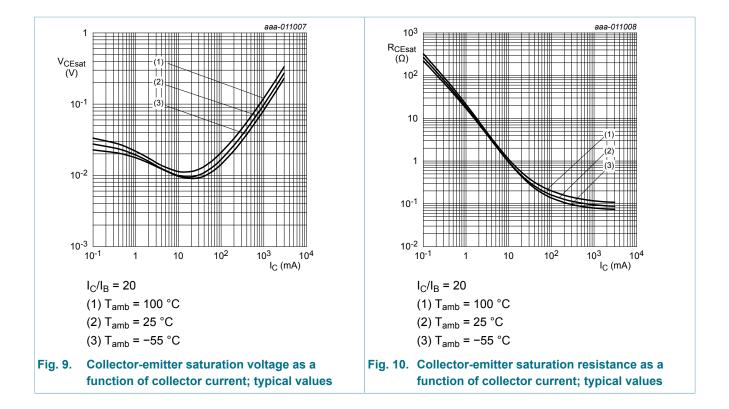
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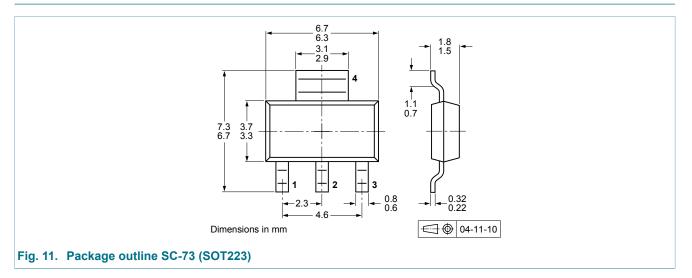
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11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



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7 3.85 3.6 3.5 - 0.3 ŧ 1.3 1.2 (4×) (4×) solder lands ł Ī | solder resist 3.9 6.1 7.65 solder paste -1 occupied area 1 Dimensions in mm 2.3 2.3 1.2 (3×) 1.3 (3×) 6.15 sot223_fr Fig. 12. Reflow soldering footprint for SC-73 (SOT223) 8.9 6.7 1.9 solder lands 4 solder resist 6.2 8.7] occupied area Dimensions in mm preferred transport ł direction during soldering 1.9 (3×) 2.7 2.7 1.9 1.1 (2×) sot223_fw Fig. 13. Wave soldering footprint for SC-73 (SOT223)

13. Soldering

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14. Revision history

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PBSS4360Z v.1	20140226	Product data sheet	-	-	

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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